NSN 5961-01-464-1836

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-1836 **Inclosure Material:** Plastic **Overall Length:** 2.800 millimeters **Terminal Length:** 2.900 millimeters **Overall Height:** 1.100 millimeters **Overall Width:** 2.800 millimeters **End Application:** 6625-01-425-2551 **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 5.0 reverse voltage, instantaneous all semiconductor and 0.5 forward voltage, dc all semiconductor **Current Rating Per Characteristic:** 35.00 milliamperes source cutoff current preset all semiconductor **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-emitter peak all semiconductor **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 125.0 degrees celsius case **Special Features:** Widebandoperation **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0